# Infrared Light Emitting Diode in SMD Plastic Package



## **OP270 Series**

- 890nm Wavelength
- Narrow Beam Angle
- High Power
- 1.9mm Water Clear Plastic Package
- Four Lead Configurations



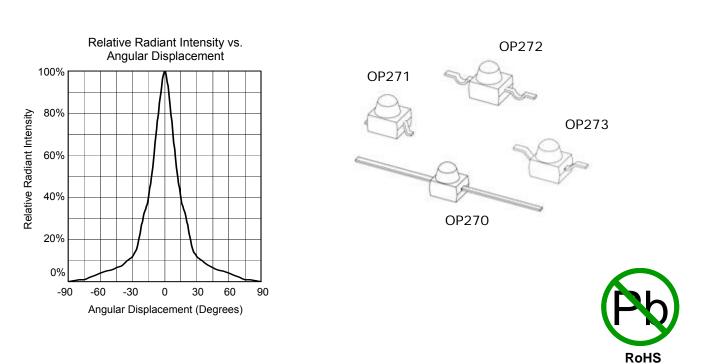
#### **Description:**

The OP270 series are GaAlAs infrared LEDs mounted in a clear plastic SMT packages. The devices incorporate an integral molded lens which enables a narrow beam angle and provides an even emission pattern. This series is available with four lead configurations and is compatible with most automated mounting equipment. The OP270 Series LEDs are mechanically and spectrally matched to the OP570 series phototransistors.

#### Applications

- Non-Contact Position Sensing
- Datum detection
- Machine automation

- Optical encoders
- IrDA
- Reflective and Transmissive Sensors





Optek reserves the right to make changes at any time in order to improve design and to supply the best product possible.

A subsidiary of TT electronics plc



#### Absolute Maximum Ratings (T<sub>A</sub> = 25° C unless otherwise noted)

PARAMETER	SYMBOL	MAXIMUM	UNITS
Continuous Forward Current	I <sub>F</sub>	50	mA
Power Dissipation	Pd	130	mW
Reverse Voltage	I <sub>R</sub>	2	V
Peak Forward Current (1µs pulse width, 300 pps)	I <sub>FP</sub>	1	A
Lead Soldering Temperature	-	260°	С
(1.6mm to epoxy for 5 sec.)	T <sub>SOL</sub>		
Operating Temperature Range	T <sub>OPR</sub>	-40°C to +85°C	
Storage Temperature Range	T <sub>STG</sub>	-40°C to +100°C	

Notes:

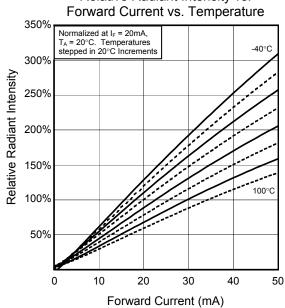
Solder time less than 5 seconds at temperature extreme. 1.

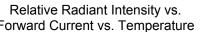
2. De-rate linearly at 2.17 mW/° C above 25° C.

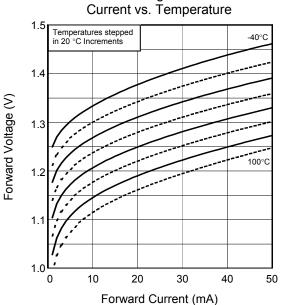
#### Electrical Characteristics (T<sub>A</sub> = 25°C unless otherwise noted)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	CONDITIONS
E <sub>e(APT)</sub>	Apertured Radiant Incidence	1.5			mW/cm <sup>2</sup>	I <sub>F</sub> = 20mA <sup>(3)</sup>
V <sub>F</sub>	Forward Voltage			1.5	V	I <sub>F</sub> = 20mA
I <sub>R</sub>	Reverse Current			100	μA	V <sub>R</sub> = 2.0V
$\lambda_{P}$	Peak Emission Wavelength		890		nm	I <sub>F</sub> = 10mA
$\Theta_{HP}$	Emission Angle at Half Power Points		25		Deg.	I <sub>F</sub> = 20mA
t <sub>r</sub> , t <sub>f</sub>	Rise and Fall Time			500	ns	$I_{F(PEAK)}$ = 100mA, PW = 10µs, 10% D.C.

E<sub>e(APT)</sub> is a measurement of the apertured radiant incidence upon a sensing area 0.081" (2.06mm) in diameter, perpendicular to and cen-3. tered on the mechanical axis of the lens, and 0.590" (14.99mm) from the measurement surface. E<sub>e(APT)</sub> is not necessarily uniform within the measured area.



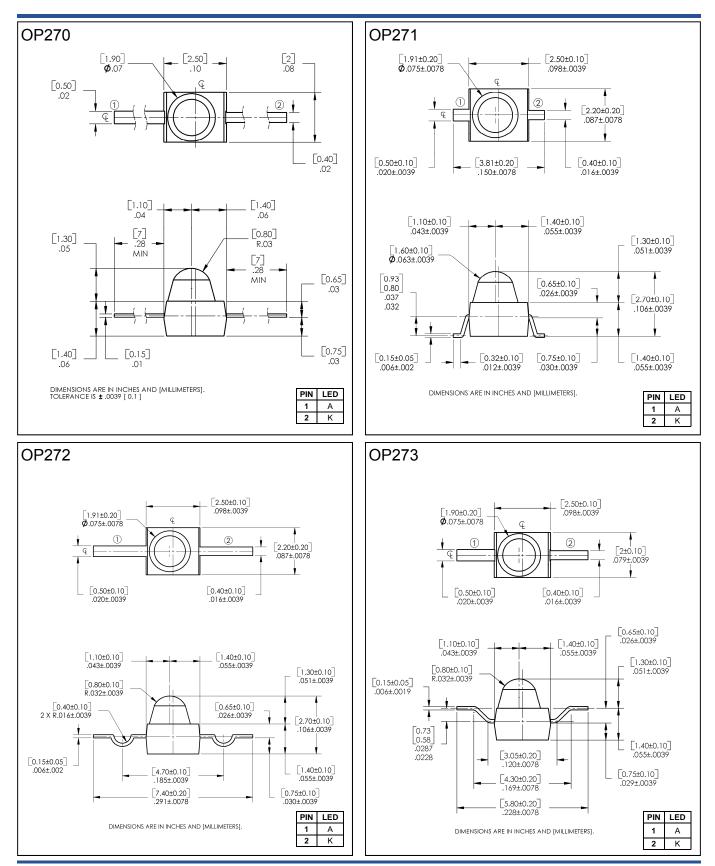




# Forward Voltage vs. Forward

### SMD Infrared LED OP270 Series





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